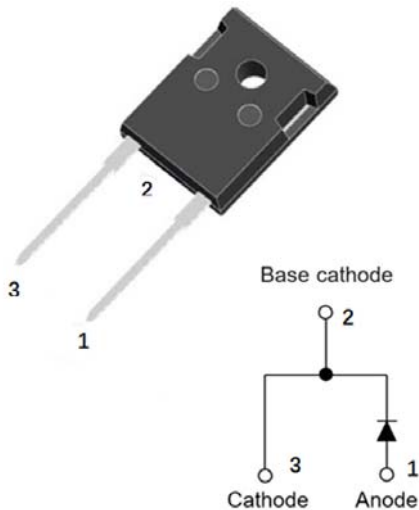


Silicon Carbide Schottky Diode

V_{RRM}	1200V
I_F (135°C)	83A
Q_C	320nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero reverse recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- **Package:** TO-247AC
- **Terminals:** Tin plated leads
- **Polarity:** As marked

■Maximum Ratings ($T_C=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112060NQG2
Reverse voltage (repetitive peak) @ $T_j=25^\circ\text{C}$	V_{RRM}	V	1200
Reverse voltage (Surge Peak) @ $T_j=25^\circ\text{C}$	V_{RSM}	V	1200
Reverse voltage (DC) @ $T_j=25^\circ\text{C}$	V_{DC}	V	1200
Continuous forward current @ $T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=150^\circ\text{C}$	I_F	A	177 83 60
Non-repetitive peak forward surge current @ $T_c=25^\circ\text{C}$, $t_p=10\text{ms}$, Half Sine Wave	I_{FSM}	A	445
Power Dissipation@ $T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	P_{TOT}	W	750 325
i^2t Value@ $T_c=25^\circ\text{C}$, $t_p=10\text{ms}$	$\int i^2 dt$	A^2S	900
Operating junction and Storage temperature range	T_j, T_{stg}	$^\circ\text{C}$	-55 to +175

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Typ.	Max.
Forward voltage drop	V_F	V	$I_F=60A, T_j=25^{\circ}C$	1.45	1.62
			$I_F=60A, T_j=175^{\circ}C$	2.0	
Reverse leakage current	I_R	μA	$V_R=1200V, T_j=25^{\circ}C$	5	50
			$V_R=1200V, T_j=175^{\circ}C$	20	
Total capacitive charge	Q_C	nC	$V_R=800V, T_j=25^{\circ}C, Q_C=\int_0^{V_R} I_C(V)dV$	320	
Total capacitance	C	pF	$V_R=0V, f=1MHZ$	4358	
			$V_R=400V, f=1MHZ$	304	
			$V_R=800V, f=1MHZ$	236	
Capacitance Stored Energy	E_C	μJ	$V_R=800V$	84	

■Thermal Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{\theta J-C}$	$^{\circ}C/W$	0.2

■Characteristics (Typical)

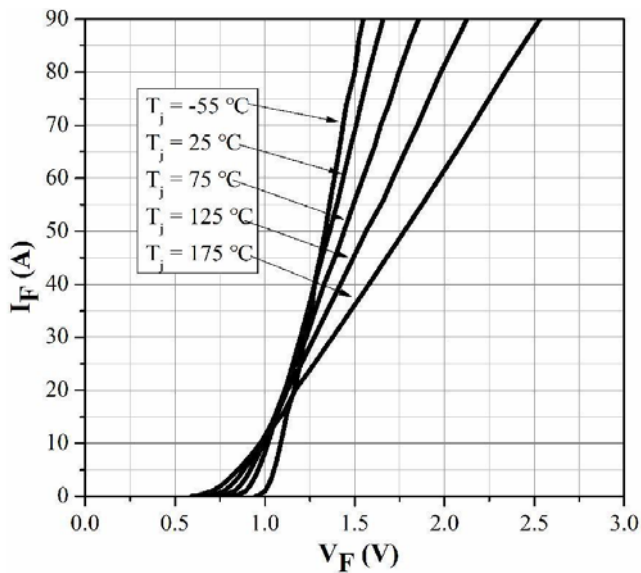


Figure 1. Forward Characteristics

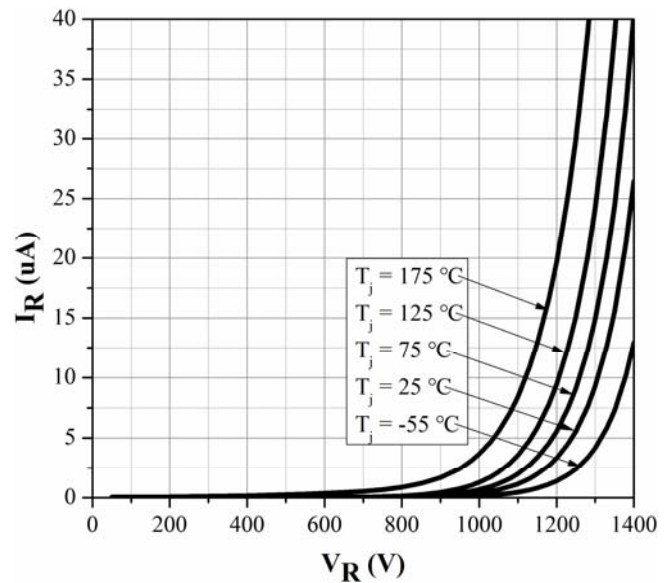


Figure2. Reverse Characteristic

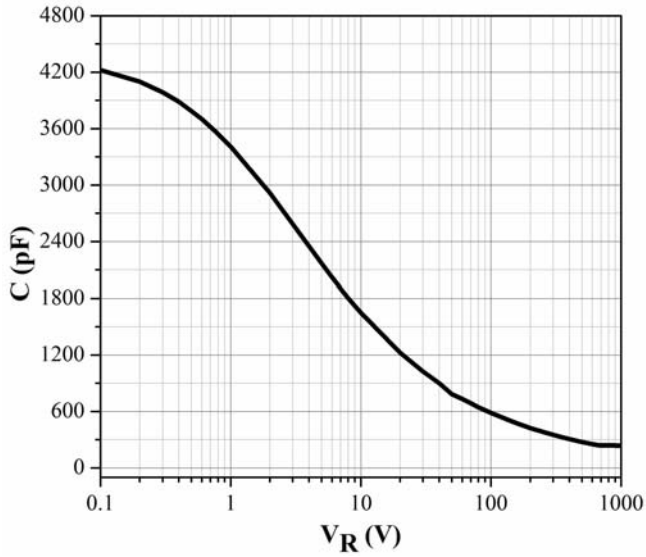


Figure 3. Capacitance vs. Reverse Voltage

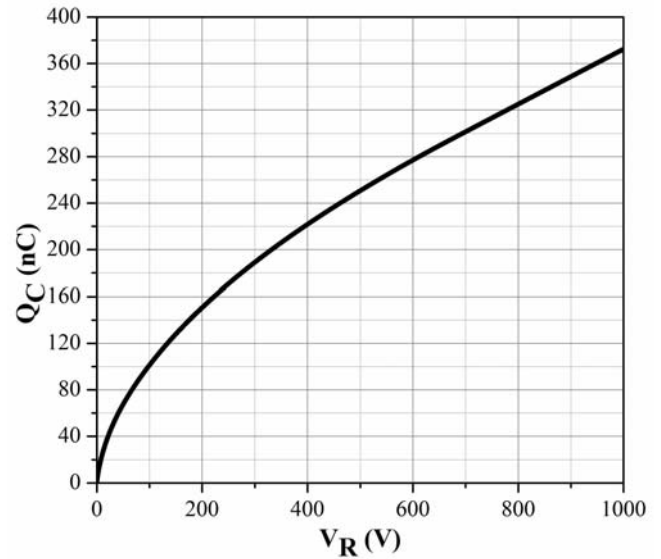


Figure 4. Total Capacitance Charge vs. Reverse Voltage

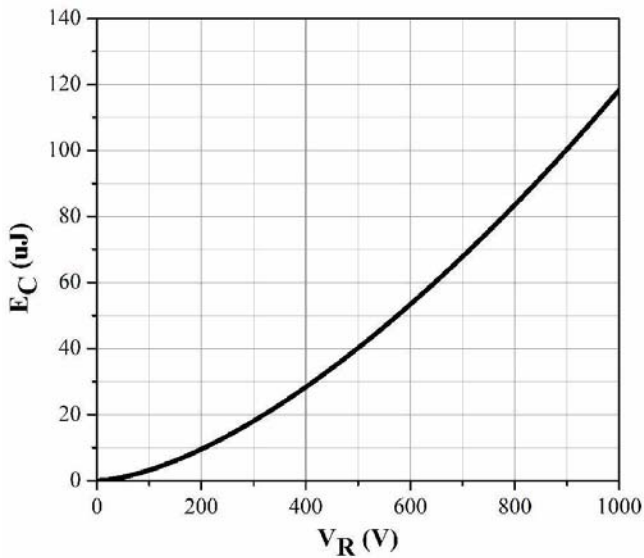


Figure 5. Capacitance Stored Energy

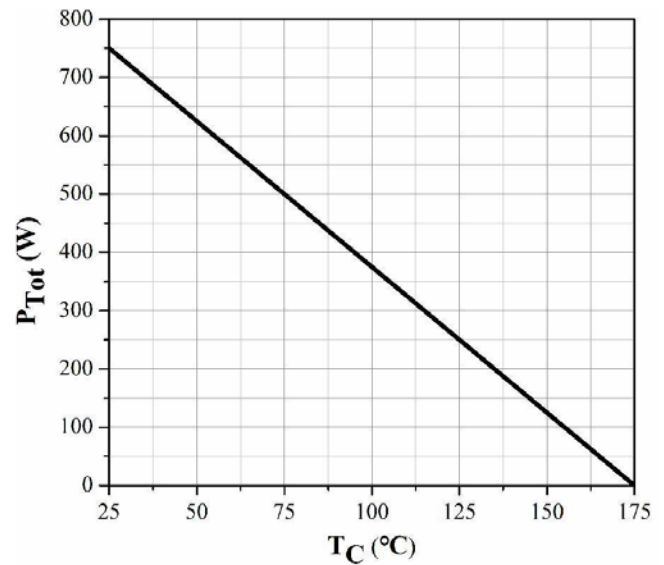


Figure 6. Power Derating

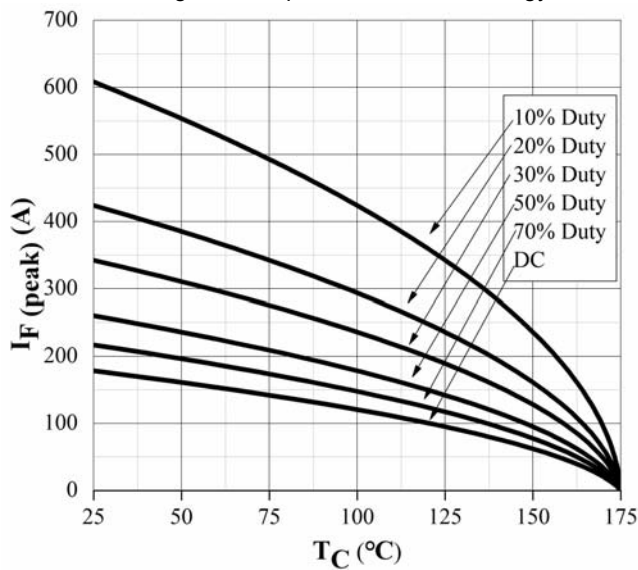


Figure 7. Current Derating

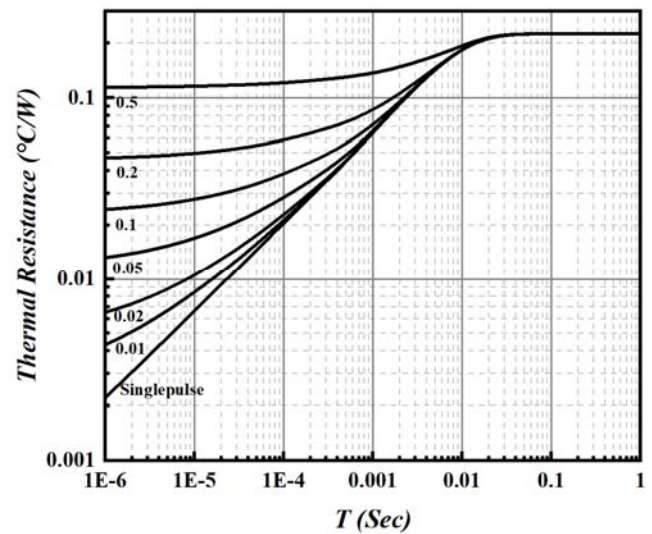
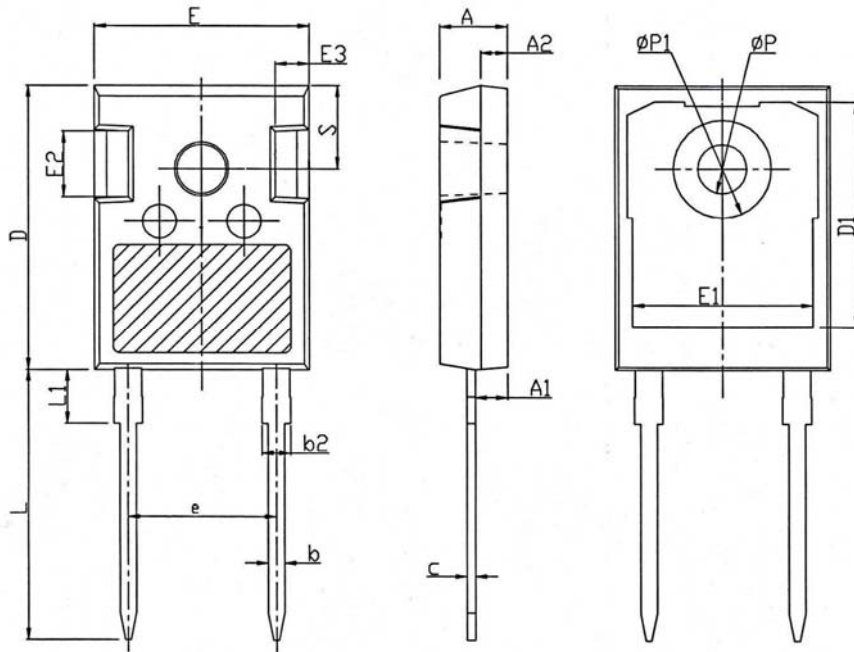


Figure 8. Transient Thermal Impedance

■Outline Dimensions



T0247-AC		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.11	1.36
b2	1.91	2.21
c	0.51	0.75
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.00	13.60
E2	4.80	5.20
E3	2.30	2.70
e	10.88BSC	
L	19.62	20.22
L1	-	4.30
φP	3.40	3.80
φP1	-	7.30
S	6.15BSC	



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